

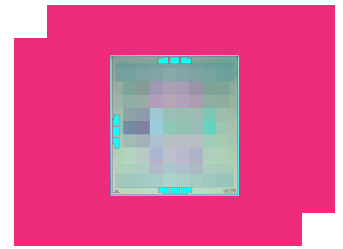
MT3H-0113HCH-2

GaAs MMIC High Dynamic Range Mixer

DEVICE OVERVIEW

General Description

The MT3H-0113H is a triple balanced passive diode mixer offering high dynamic range, low conversion loss, and excellent repeatability. As with all T3 mixers, this mixer offers unparalleled nonlinear performance in terms of IIP3, P1dB, and spurious performance with a flexible LO drive requirement from +16 dBm to +24 dBm. RF, LO, and IF ports are all operated single ended due to integrated baluns. The MT3H-0113H is available as a wire bondable chip or an SMA connectorized package. The MT3H-0113H is a superior alternative to Marki Microwave carrier and packaged T3 mixers.



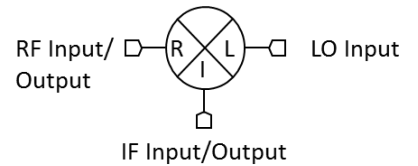
Features

- Broadband, Overlapping RF, LO and IF
- RoHS Compliant
- Square-Wave LO delivers Industry-Leading Spurious, IP3, and P1dB Performance

Applications

N/A

Functional Block Diagram



Part Ordering Options

Part Number	Description	Package	Connectors	Green Status	Product Lifecycle	Export Classification
MT3H-0113HS	GaAs MMIC High Dynamic Range Mixer	S	Standard	REACH RoHS	Released	EAR99
MT3H-0113HCH-2	GaAs MMIC High Dynamic Range Mixer	CH	-	REACH RoHS	Released	EAR99

Table Of Contents

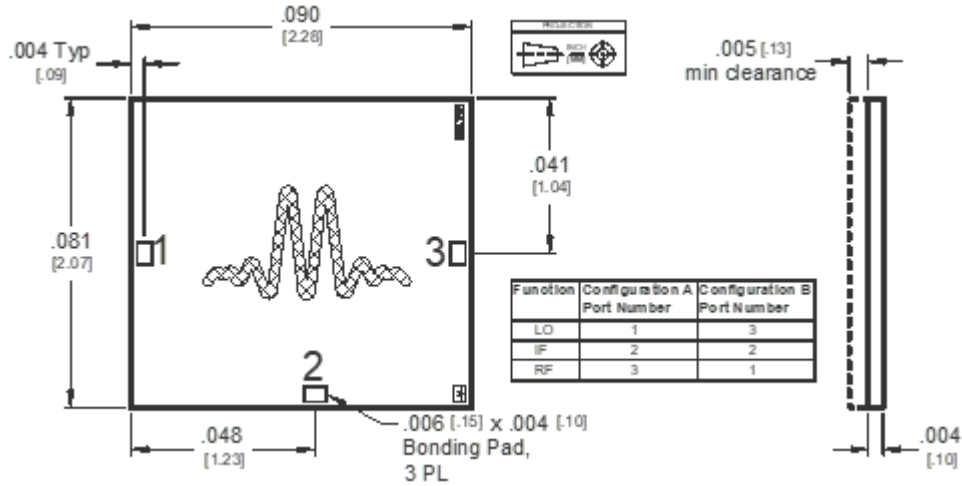
- **Device Overview**
 - General Description
 - Features
 - Applications
 - Functional Block Diagram
- **Port Configuration and Functions**
 - Port Diagram
 - Port Functions
- **Revision History**
- **Specifications**
 - Absolute Maximum Ratings
 - Package Information
 - Recommended Operating Conditions
 - Electrical Specifications
 - Typical Performance
 - MT3H-0113HS Typical Performance Plots
 - Spur Tables
- **Die Mounting Recommendations**
 - Mounting and Bounding Recommendations
- **Mechanical Data**
 - Outline Drawing
- **Notes**

Revision History

Revision Code	Revision Date	Comment
-	2017-01-01	Initial Release
A	2019-01-01	Revised square wave LO IP3 plots. End note 5 updated to reflect new test condition.

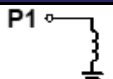
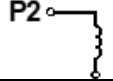
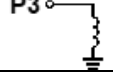
Port Configuration and Functions

Port Diagram

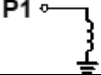
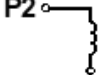
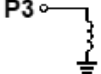


Port Functions

Configuration A

Port	Function	Description	Equivalent Circuit for Package
Port 1	LO	Port 1 is DC short and AC matched to 50 Ω from 0.8 to 13 GHz. Blocking capacitor is optional.	
Port 2	IF	Port 2 is DC open. Blocking capacitor is optional.	
Port 3	RF	Port 3 is DC short and AC matched to 50 Ω from 0.8 to 13 GHz. Blocking capacitor is optional.	

Configuration B

Port	Function	Description	Equivalent Circuit for Package
Port 1	RF	Port 1 is DC short and AC matched to 50 Ω from 0.8 to 13 GHz. Blocking capacitor is optional.	
Port 2	IF	Port 2 is DC open. Blocking capacitor is optional.	
Port 3	LO	Port 3 is DC short and AC matched to 50 Ω from 0.8 to 13 GHz. Blocking capacitor is optional.	

Specifications

Absolute Maximum Ratings

Parameter	Maximum Rating	Unit
Maximum Operating Temperature	100	°C
Maximum Storage Temperature	125	°C
Minimum Operating Temperature	-55	°C
Minimum Storage Temperature	-65	°C
RF Power Handling (RF+LO)	30	dBm

Package Information

Parameter	Details	Rating
Dimensions	-	2.28x2.07 mm

Recommended Operating Conditions

Parameter	Min	Nominal	Max	Unit
LO Input Power	16	-	24	-

Electrical Specifications

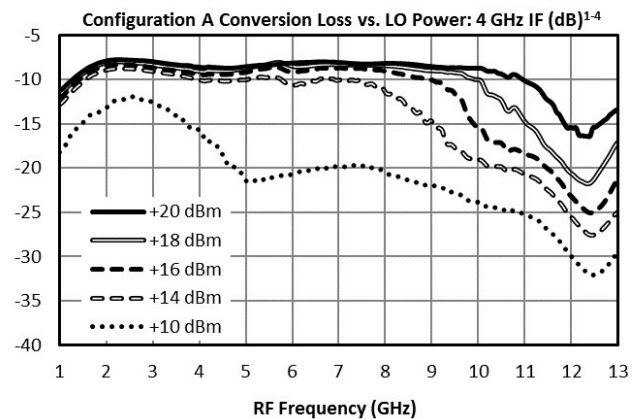
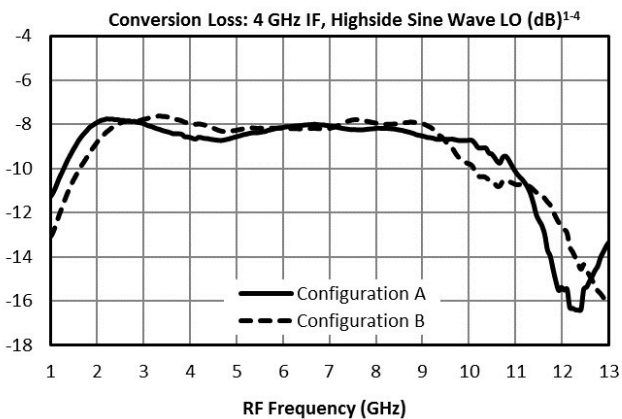
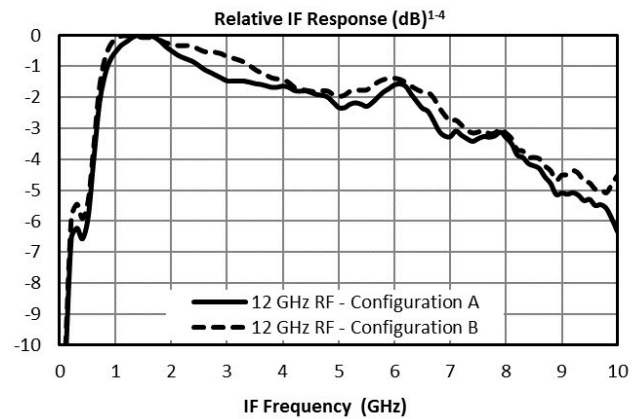
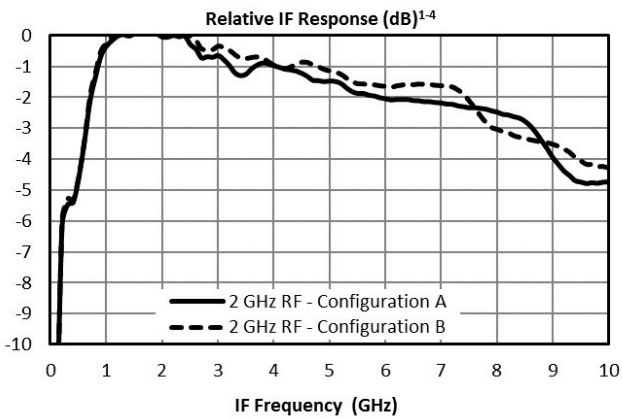
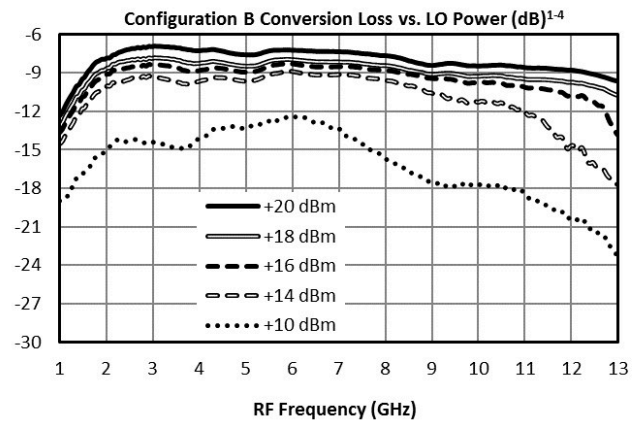
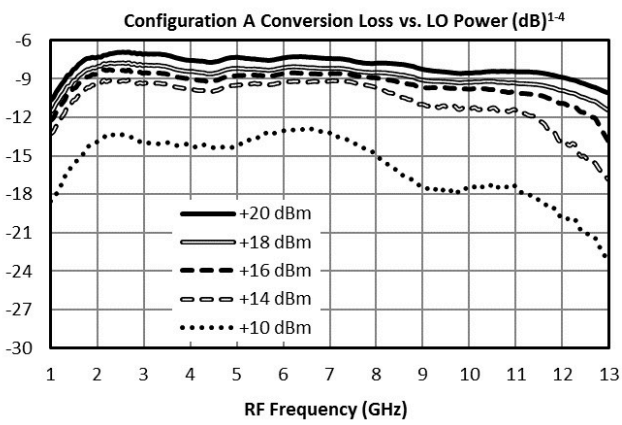
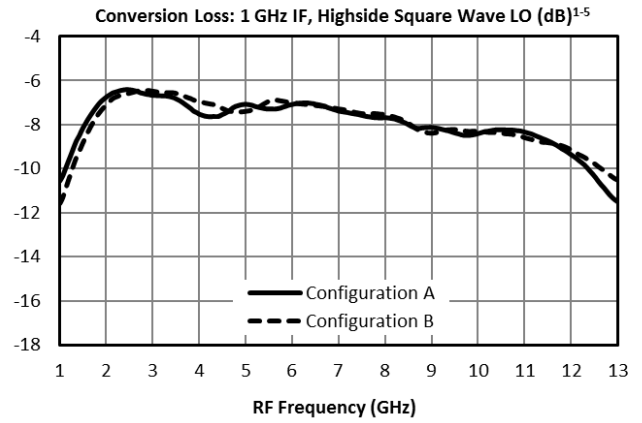
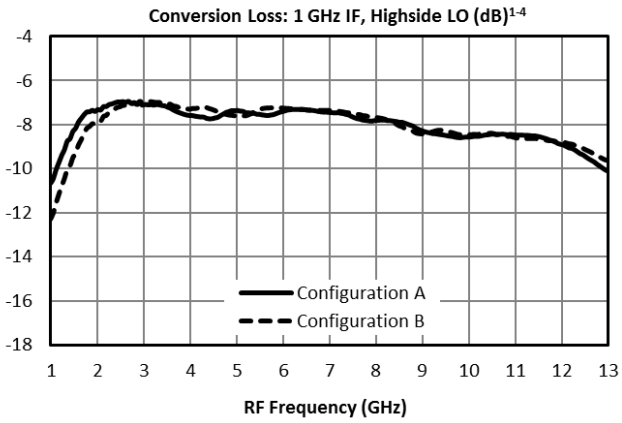
Specifications guaranteed from -55 to +100°C, measured in a 50Ω system. All bare die are 100% DC tested and 100% visually inspected. RF testing is performed on a sample basis to verify conformance to datasheet guaranteed specifications. Consult factory for more information.

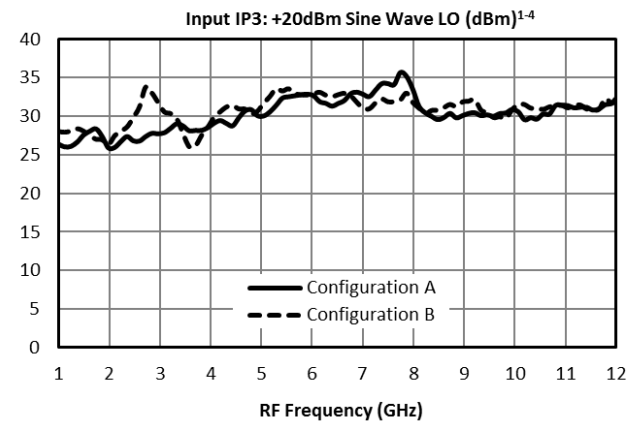
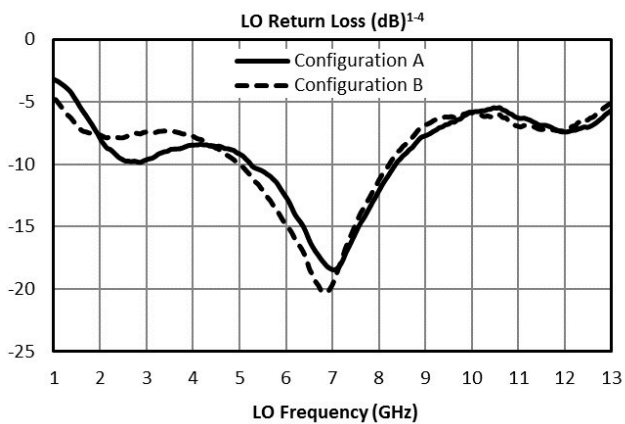
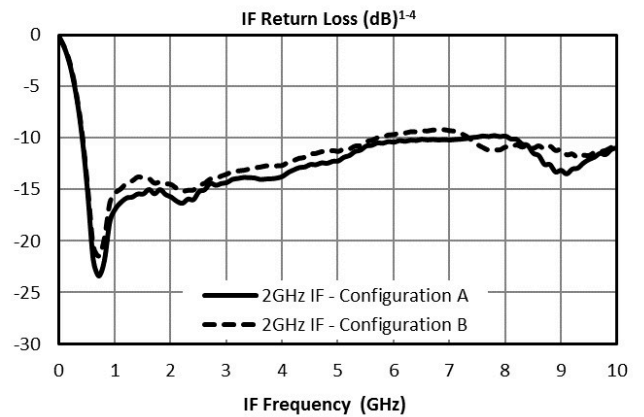
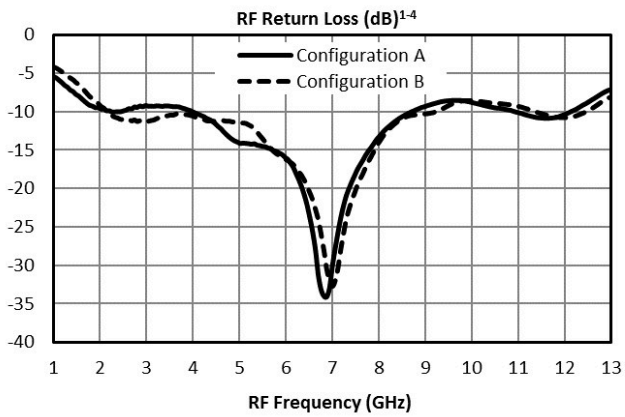
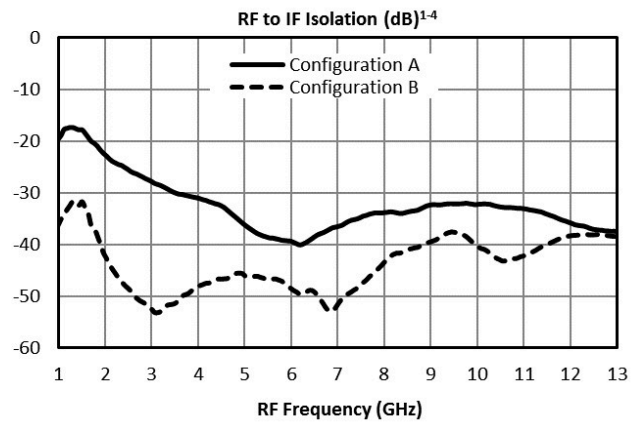
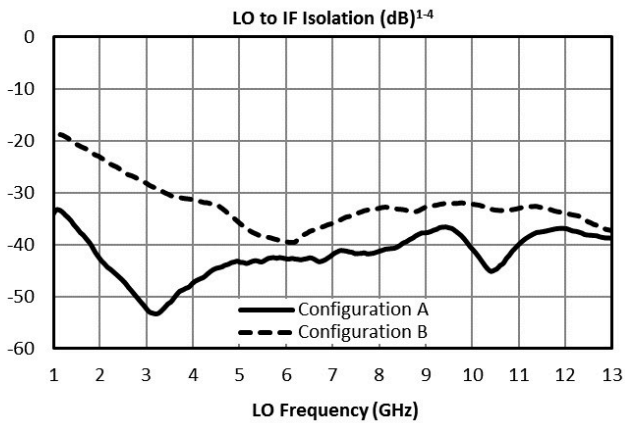
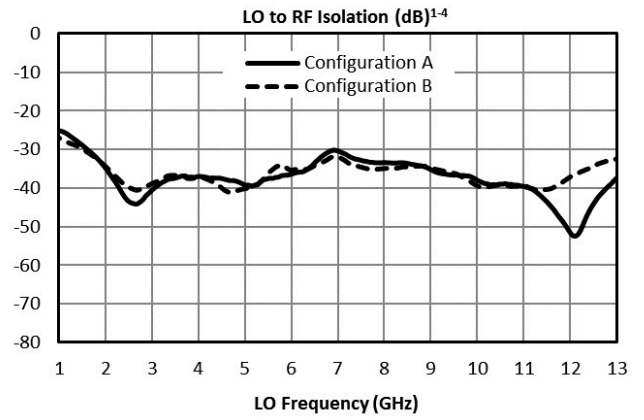
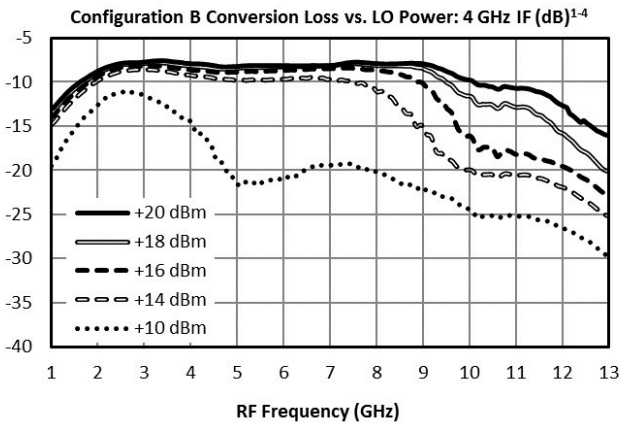
Parameter	Port Configuration	Test Conditions	Min	Typ	Max	Unit
Conversion Loss ¹	A	LO/RF=1.5-13 GHz IF=0.8-1 GHz LO drive level=20dBm	-	8	11	dB
Input IP3 ²	A	LO/RF=1.5-13 GHz IF=0.8-8.5 GHz LO drive level=16-24dBm	-	28	-	dBm
Conversion Loss ³	B	LO/RF=1.5-13 GHz IF=1-8.5 GHz LO drive level=20dBm	-	11.5	-	dB
Input IP3 ⁴	B	LO/RF=1.5-13 GHz IF=0.8-8.5 GHz LO drive level=16-24dBm	-	29	-	dBm
IF Frequency Range	-	-	0.8	-	8.5	GHz
Isolation, LO to RF	-	-	-	37	-	dB
LO Frequency Range	-	-	1.5	-	13	GHz
RF Frequency Range	-	-	1.5	-	13	GHz

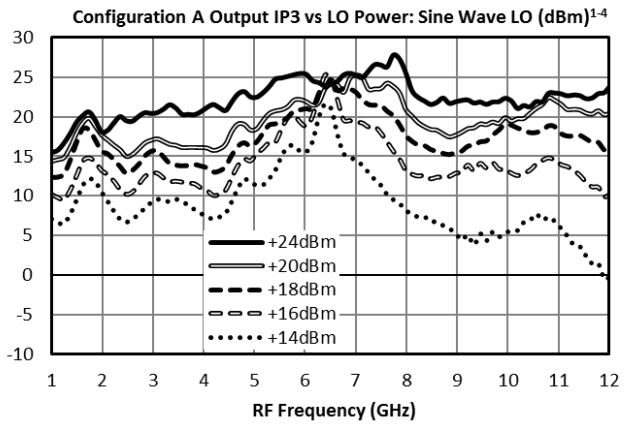
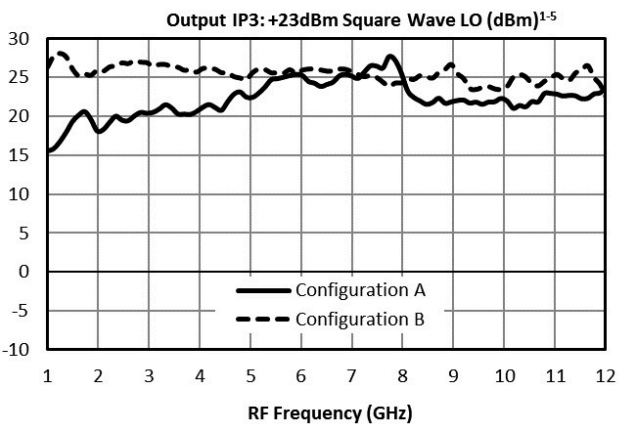
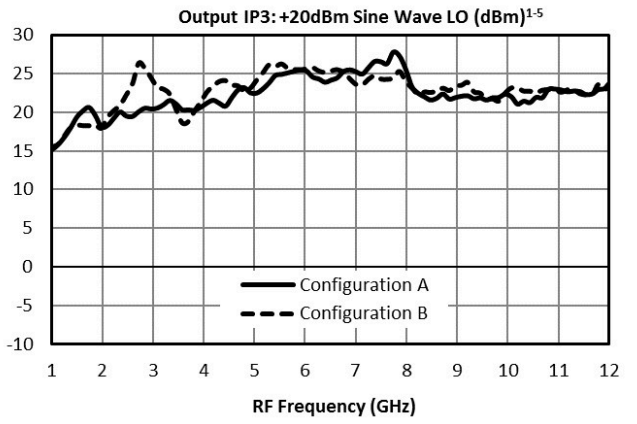
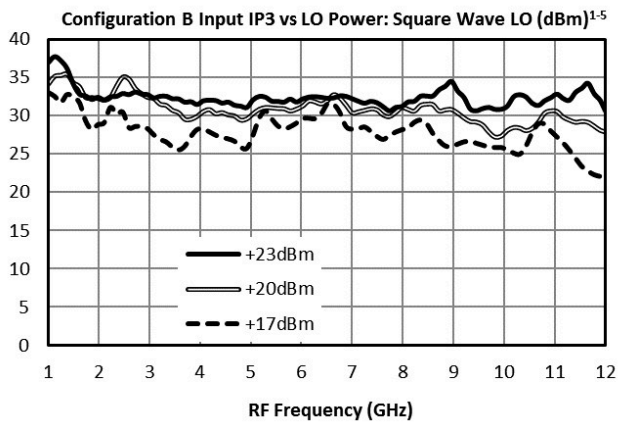
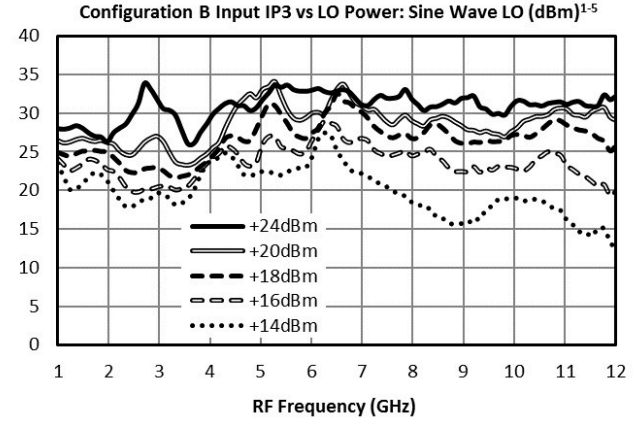
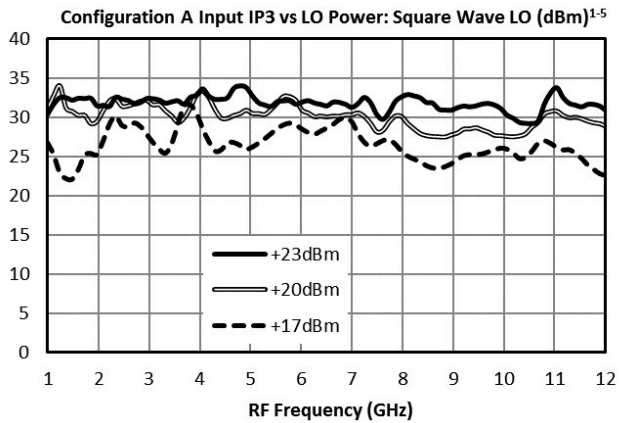
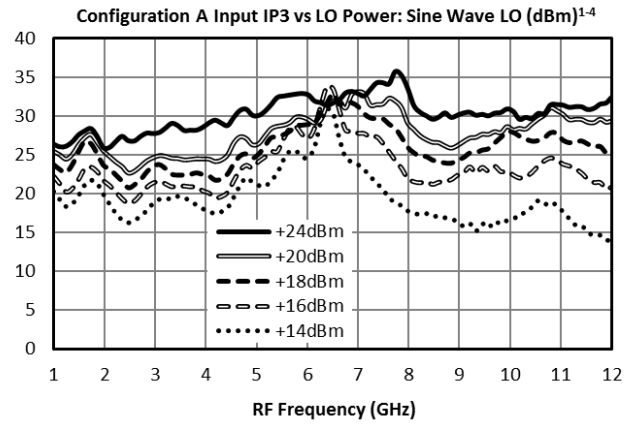
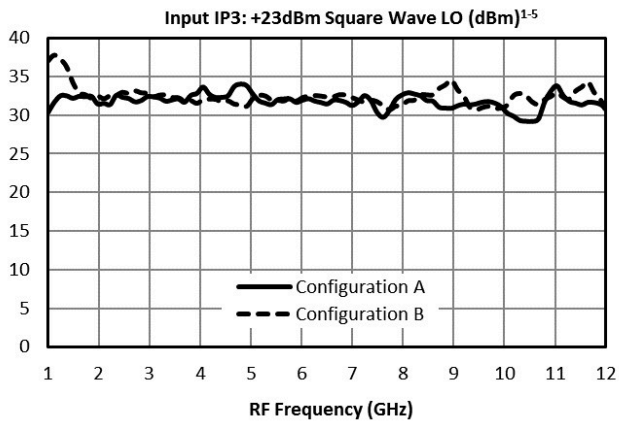
[1][3] Measured Conversion Loss measured at 1 GHz fixed IF.

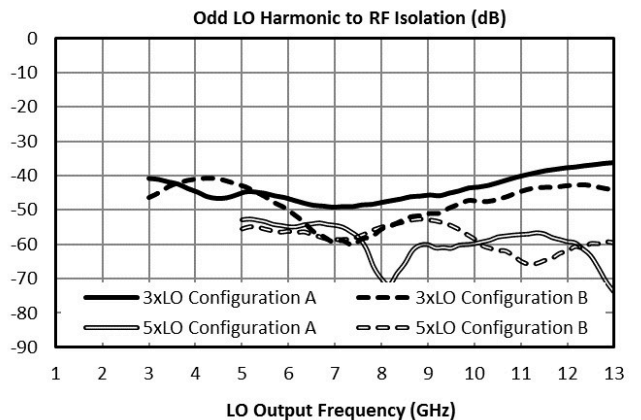
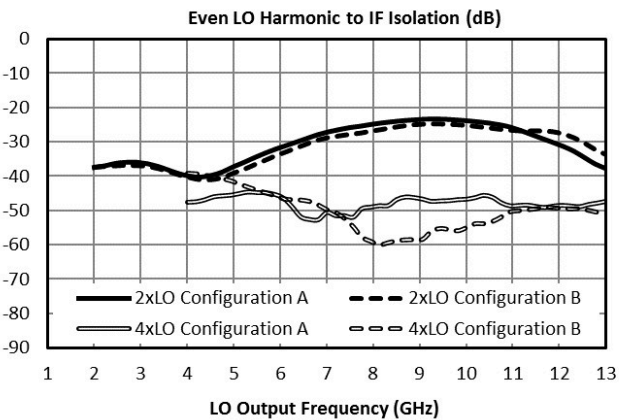
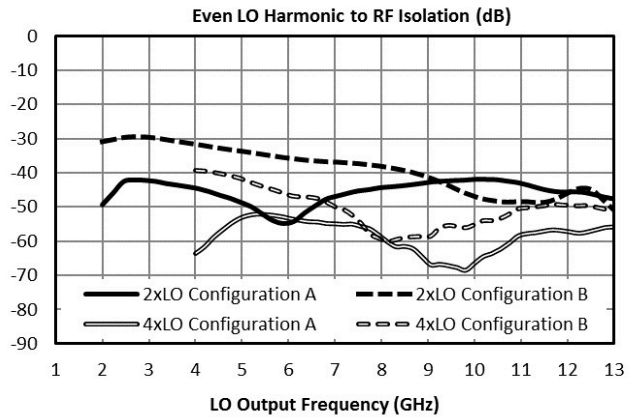
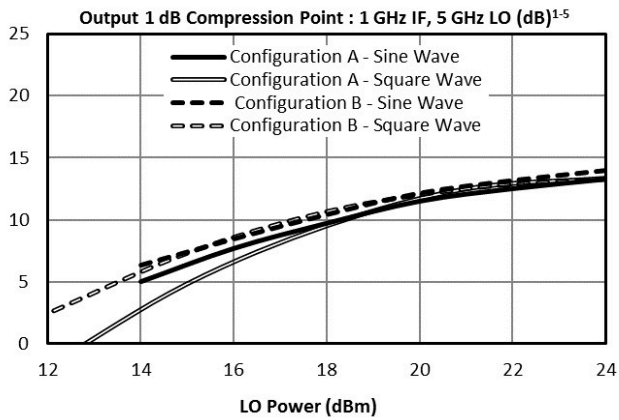
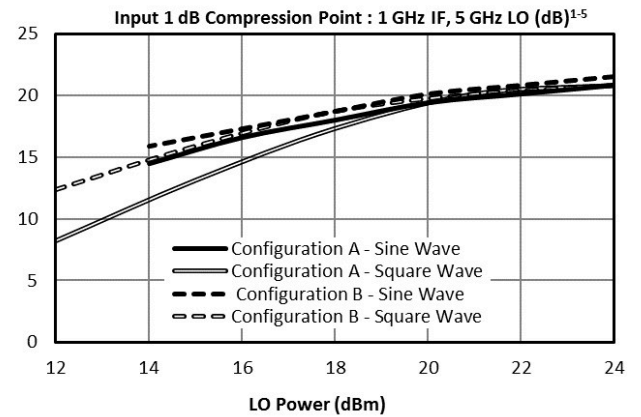
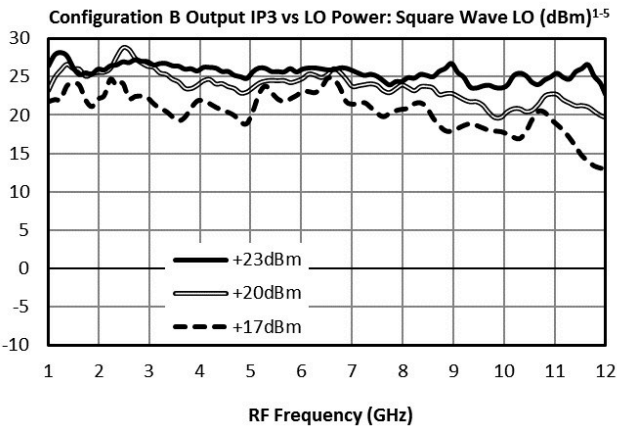
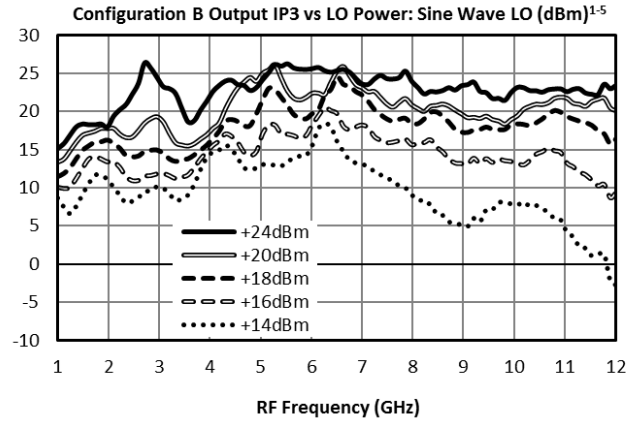
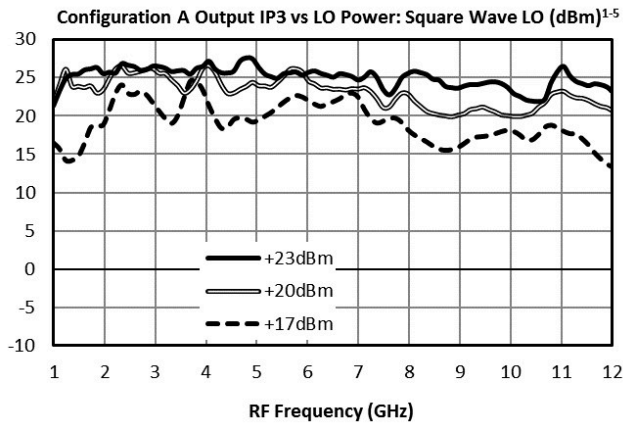
[2][4] IP3 depends on LO drive conditions

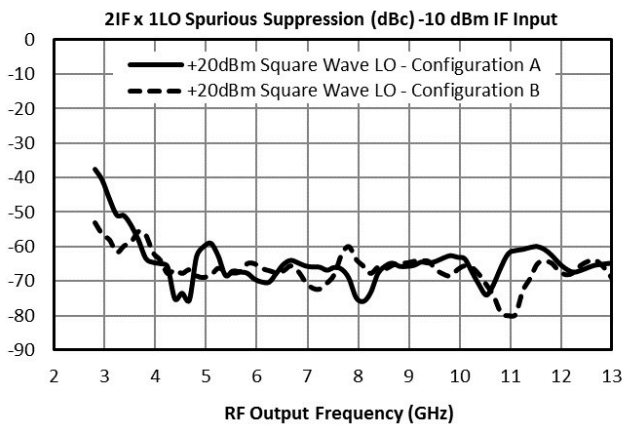
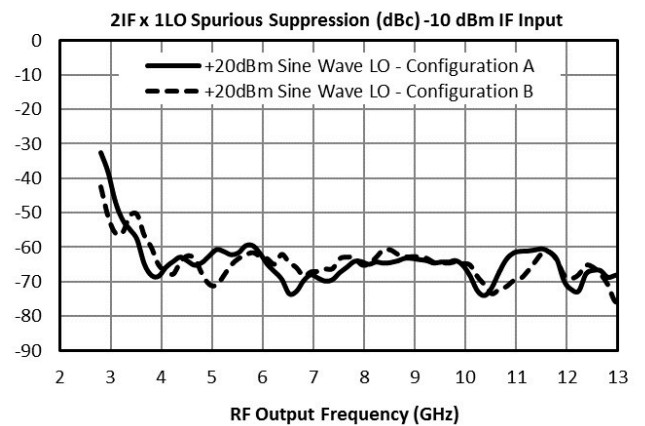
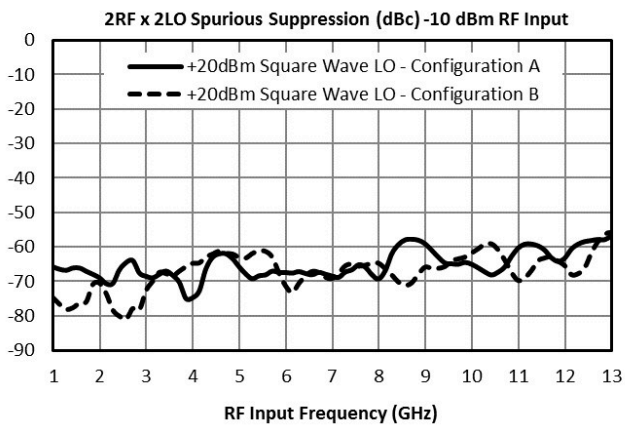
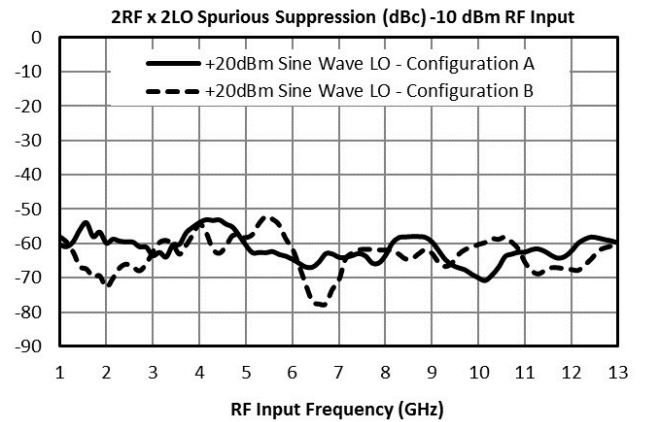
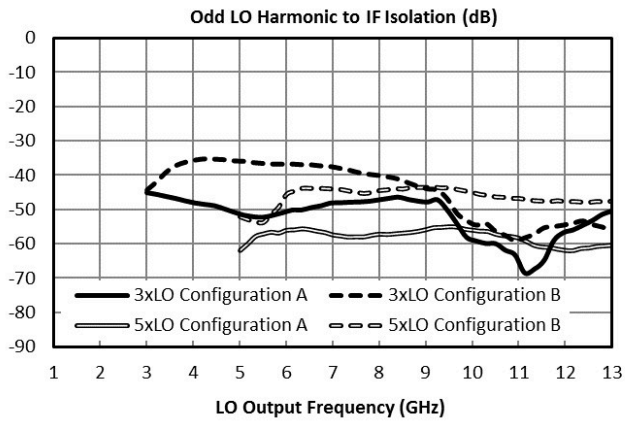
Typical Performance





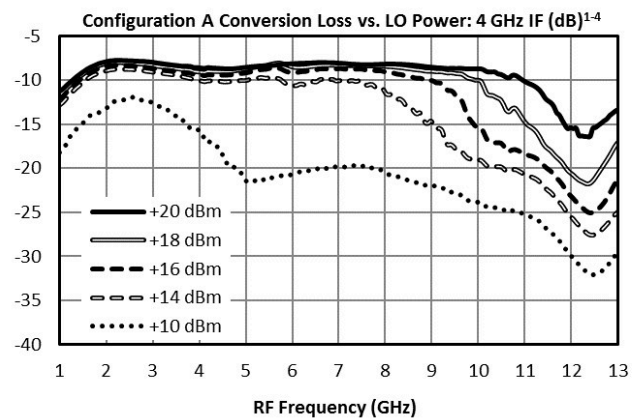
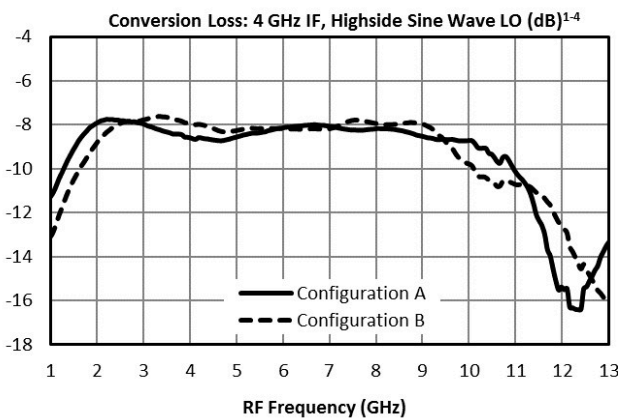
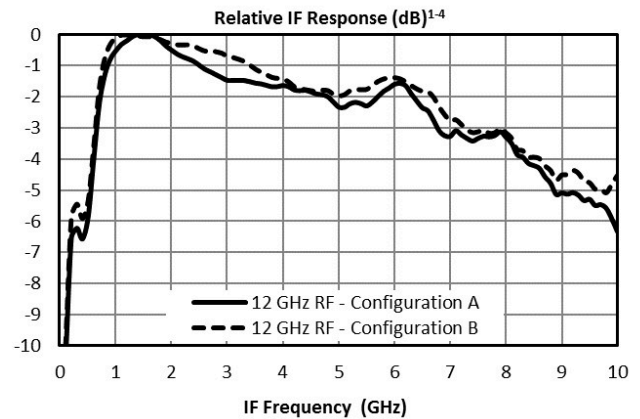
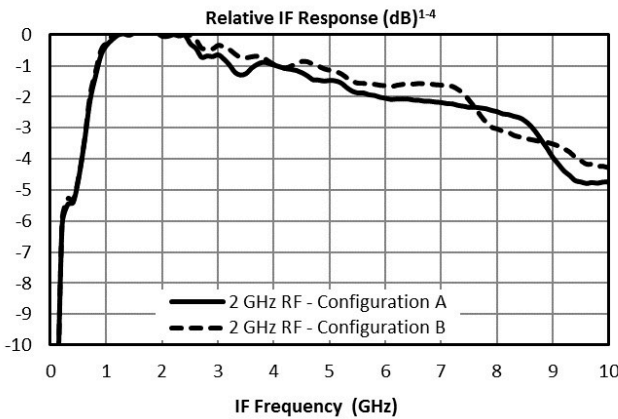
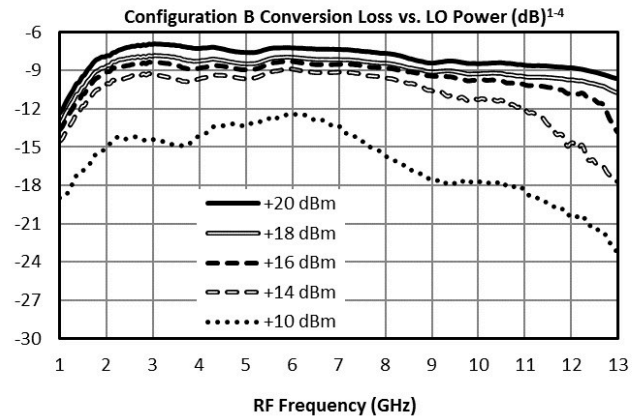
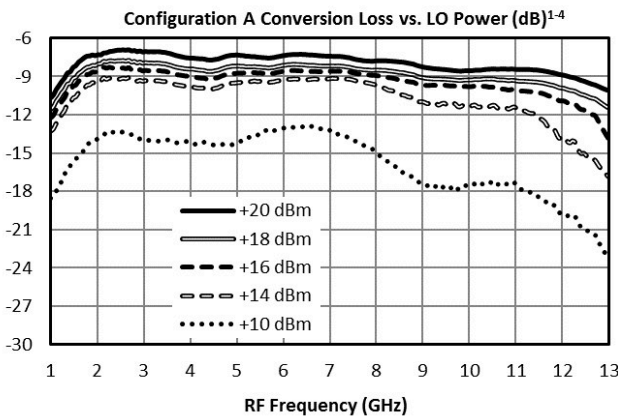
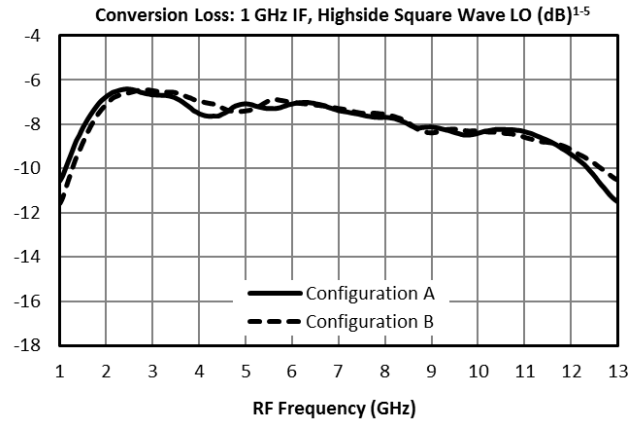
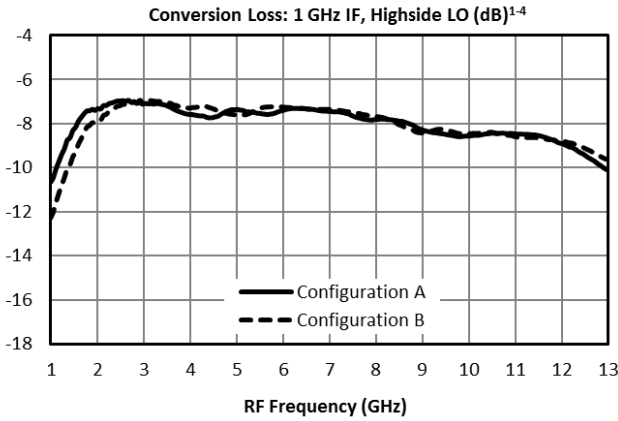


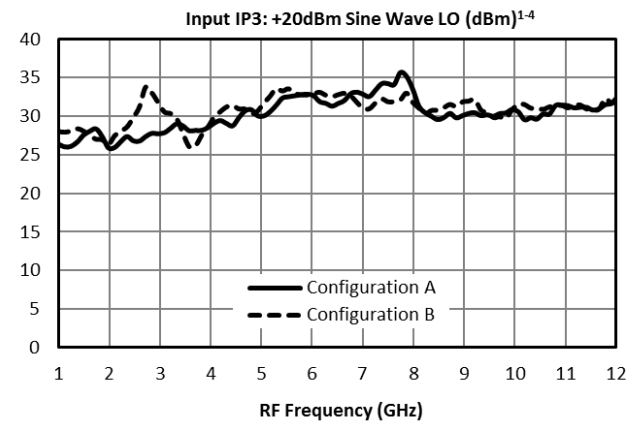
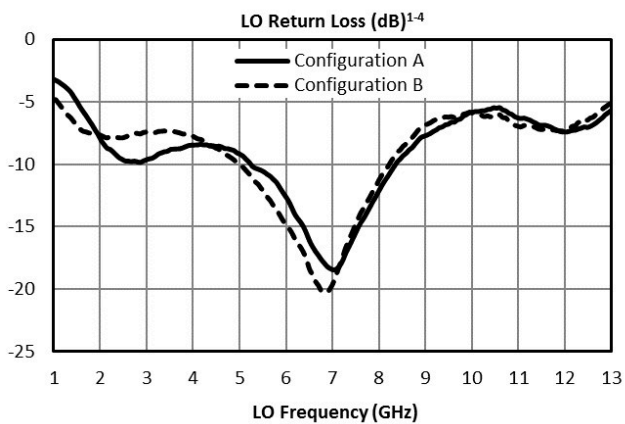
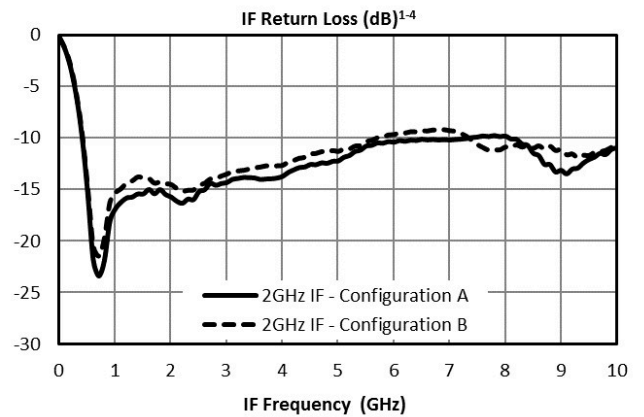
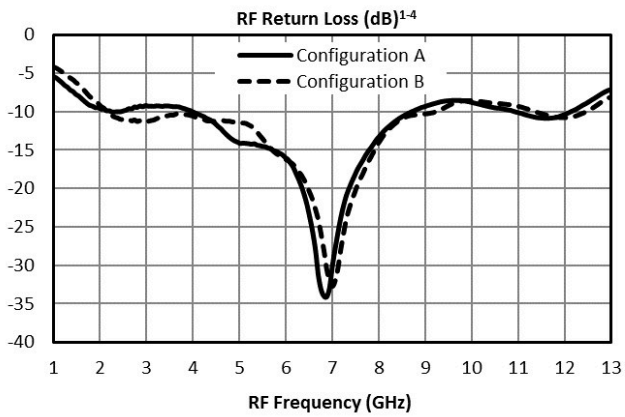
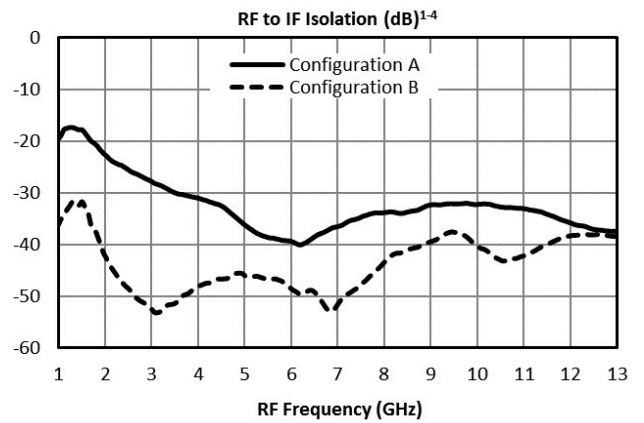
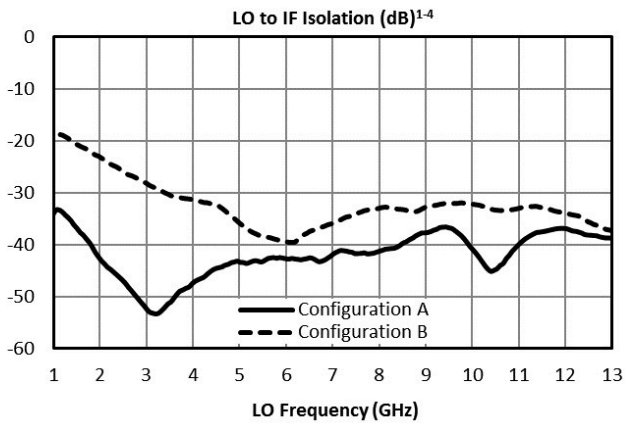
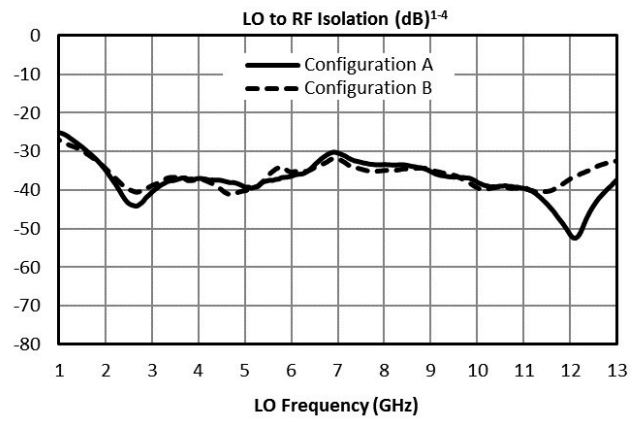
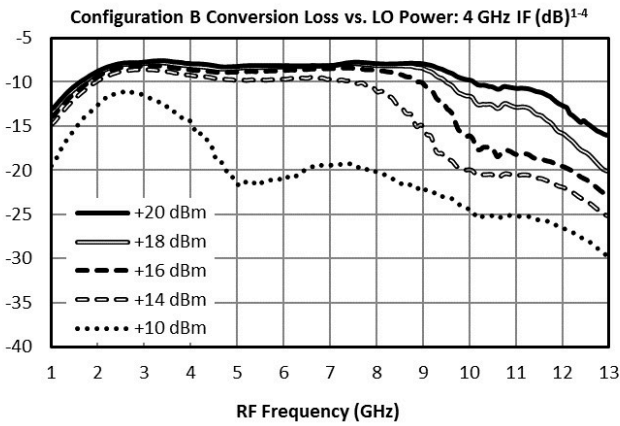


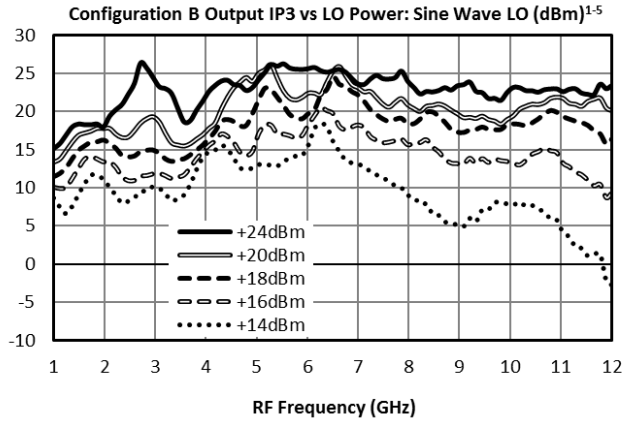
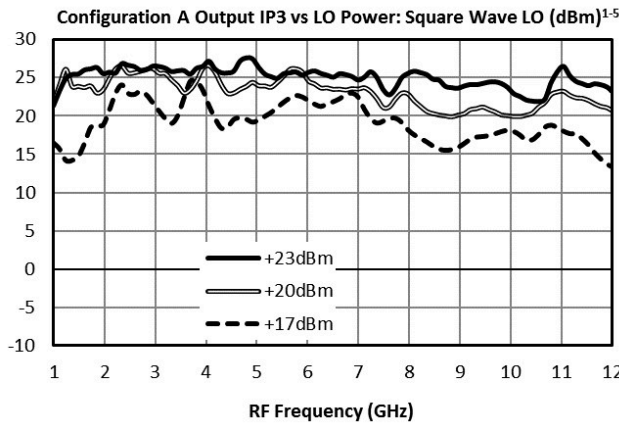
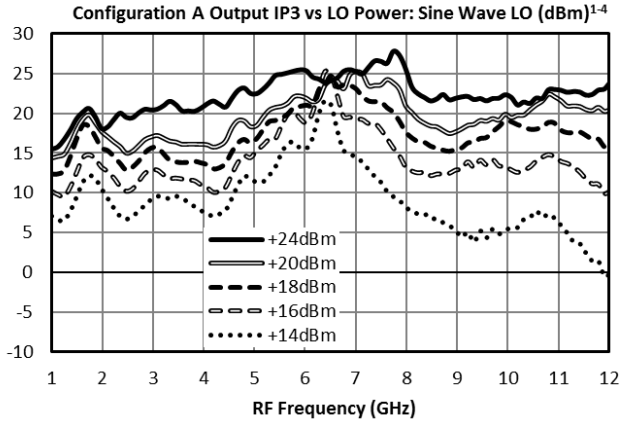
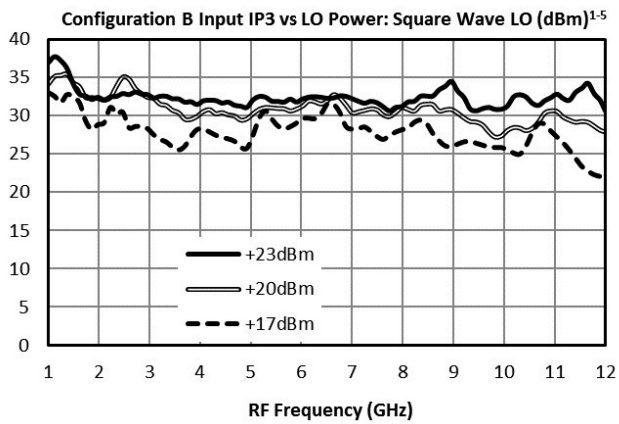
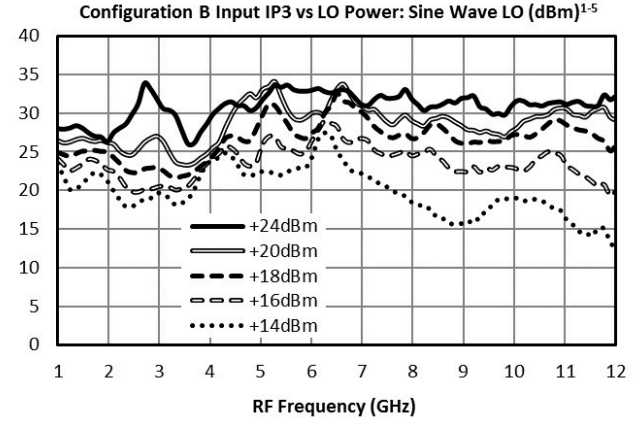
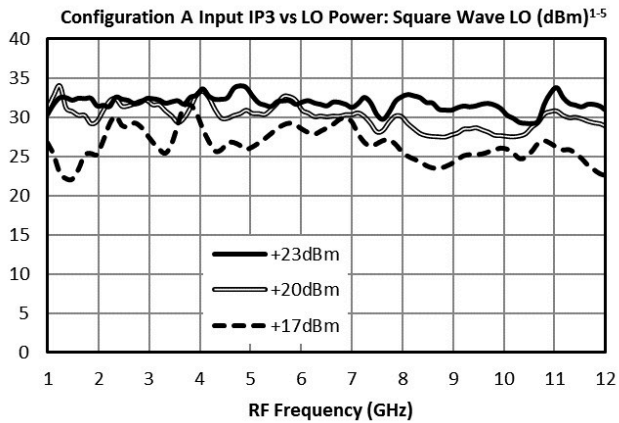
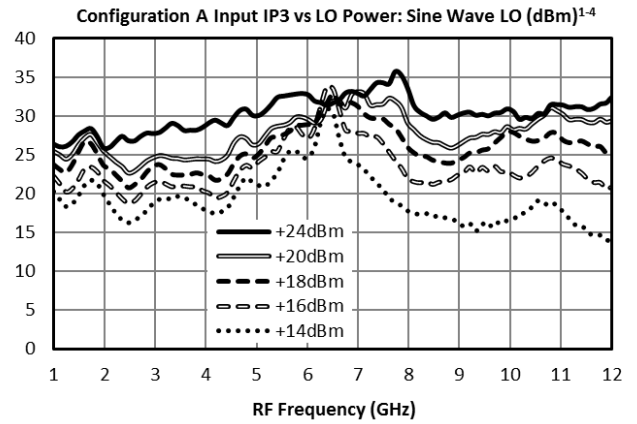
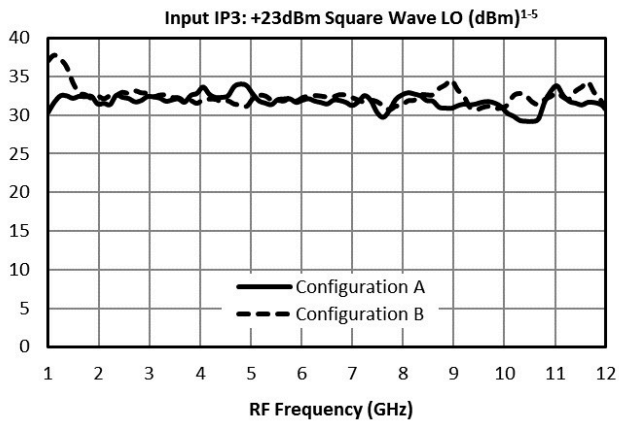


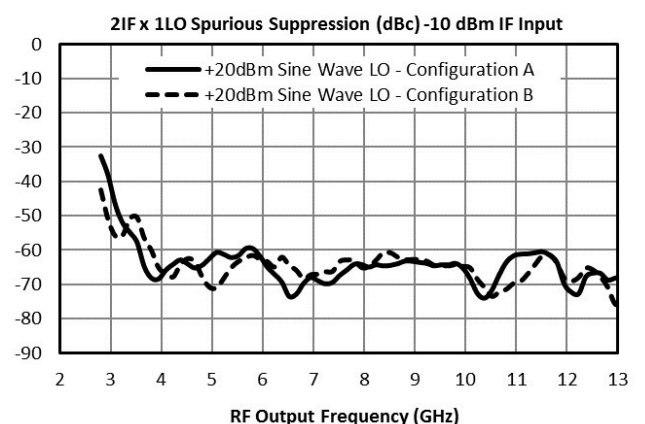
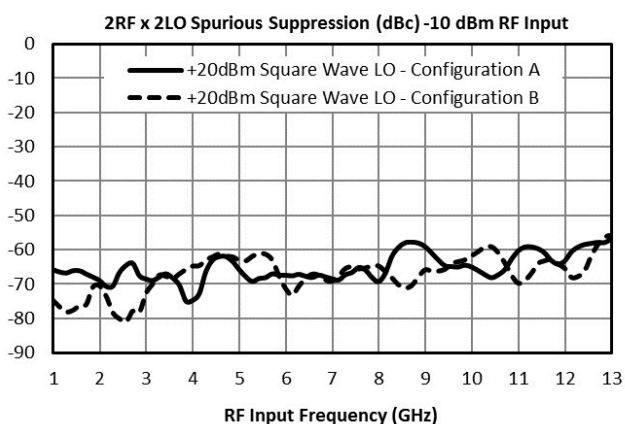
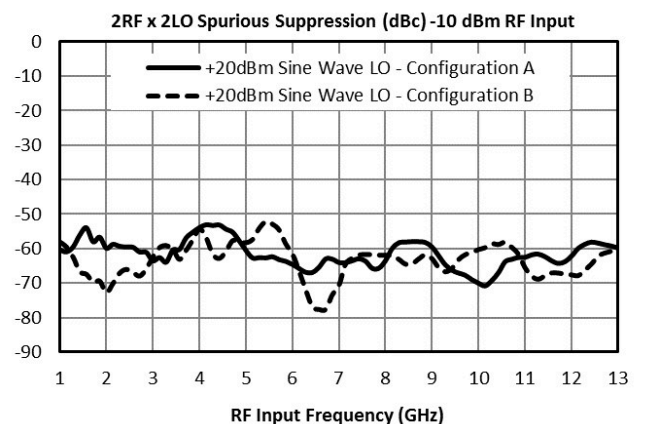
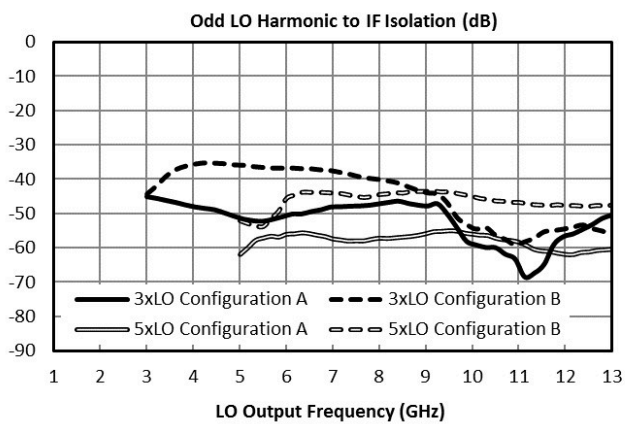
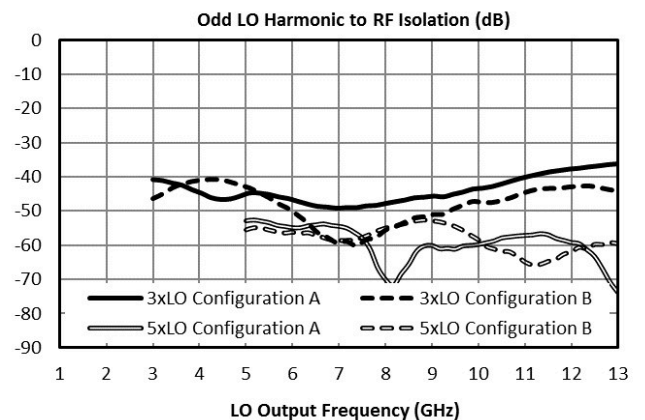
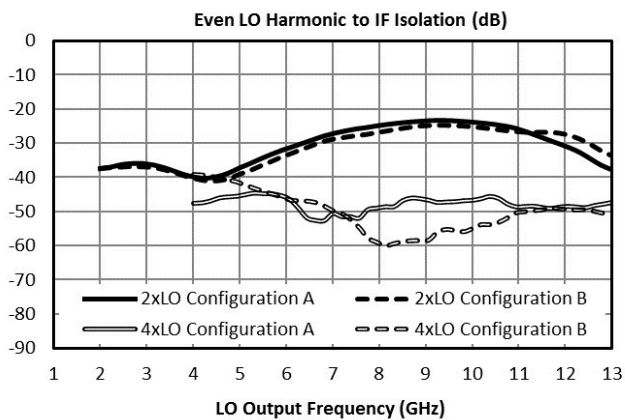
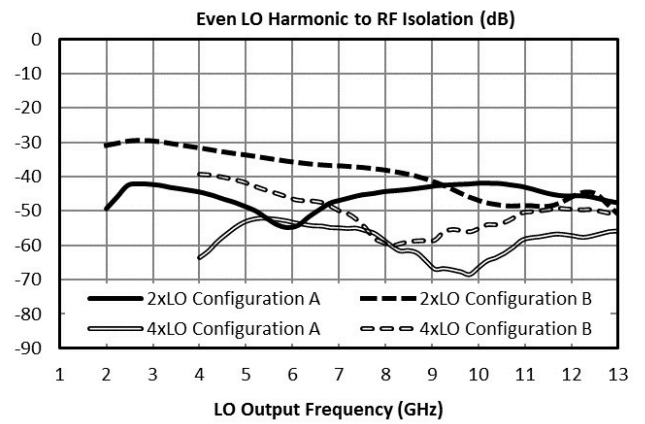
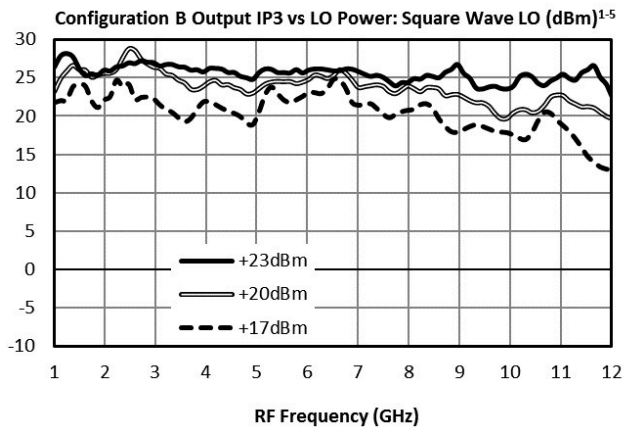
MT3H-0113HS - Typical Performance Plots

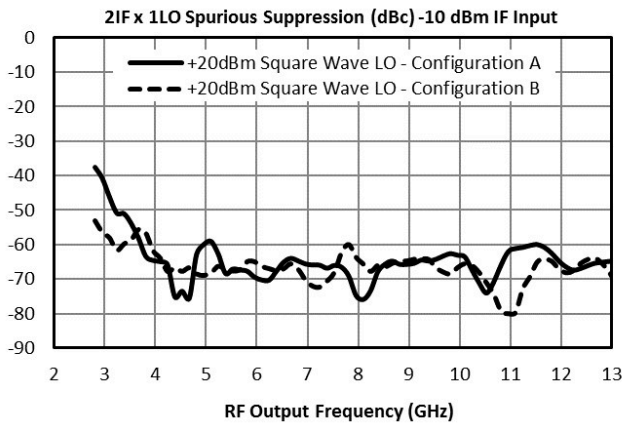
Performance plots for the connectorized module are shown for measurements where directly probed measurements of the die are unavailable. Note that the following measurements include losses from connectors and microstrip traces.











Spur Table

Downconversion Spurious Suppression

Spurious data is taken by selecting RF and LO frequencies (+mLO+nRF) within the RF/LO bands, to create a spurious output within the IF band. The mixer is swept across the full spurious band and the mean is calculated. The numbers shown in the table below are for a -10 dBm RF input. Spurious suppression is scaled for different RF power levels by (n-1), where “n” is the RF spur order. For example, the 2RFx2LO spur is 60 dBc for the A configuration for a -10 dBm input, so a -20 dBm RF input creates a spur that is (2-1) x (-10 dB) dB lower, or 70 dBc.

Typical Downconversion Spurious Suppression (dBc): A Configuration (B Configuration), Sine Wave LO ⁶

-10 dBm RF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xRF	27 (32)	Reference	27 (35)	20 (18)	22 (32)	28 (33)
2xRF	59 (59)	61 (58)	60 (62)	58 (55)	56 (59)	59 (53)
3xRF	106 (100)	83 (85)	93 (92)	77 (79)	92 (94)	126 (134)
4xRF	125 (127)	145 (145)	124 (126)	124 (123)	122 (122)	123 (123)
5xRF	159 (164)	150 (156)	153 (155)	149 (149)	154 (154)	143 (143)

Typical Downconversion Spurious Suppression (dBc): A Configuration (B Configuration), Square Wave LO ⁶

-10 dBm RF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xRF	26 (32)	Reference	25 (32)	16 (12)	22 (31)	29 (29)
2xRF	62 (58)	62 (59)	63 (65)	60 (58)	61 (63)	64 (59)
3xRF	103 (106)	90 (91)	97 (99)	83 (84)	93 (99)	136 (135)
4xRF	129 (129)	145 (145)	129 (134)	131 (131)	128 (129)	126 (126)
5xRF	166 (167)	154 (159)	154 (160)	154 (157)	157 (161)	151 (155)

Upconversion Spurious Suppression

Spurious data is taken by mixing an input within the IF band, with LO frequencies (+mLO+nIF), to create a spurious output within the RF output band. The mixer is swept across the full spurious output band and the mean is calculated. The numbers shown in the table below are for a -10 dBm IF input. Spurious suppression is scaled for different IF input power levels by (n-1), where “n” is the IF spur order. For example, the 2IFx1LO spur is typically 62 dBc for the A configuration for a -10 dBm input, so a -20 dBm IF input creates a spur that is (2-1) x (-10 dB) dB lower, or 72 dBc.

Typical Upconversion Spurious Suppression (dBc): A Configuration (B Configuration), Sine Wave LO ⁶

-10 dBm IF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xIF	20 (27)	Reference	28 (35)	18 (17)	26 (37)	21 (23)
2xIF	57 (49)	62 (64)	60 (54)	58 (60)	51 (46)	53 (53)
3xIF	91 (87)	87 (87)	88 (90)	77 (77)	76 (88)	72 (76)
4xIF	111 (111)	124 (125)	119 (120)	118 (120)	117 (113)	112 (116)
5xIF	142 (138)	149 (152)	151 (151)	139 (140)	140 (143)	131 (135)

Typical Upconversion Spurious Suppression (dBc): A Configuration (B Configuration), Square Wave LO ⁶

-10 dBm IF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
1xIF	20 (27)	Reference	30 (32)	16 (12)	22 (31)	29 (29)
2xIF	57 (49)	62 (64)	58 (54)	60 (58)	61 (63)	64 (59)
3xIF	91 (87)	88 (89)	92 (97)	83 (84)	93 (99)	136 (135)
4xIF	111 (111)	124 (125)	122 (127)	131 (131)	128 (129)	126 (126)
5xIF	142 (138)	149 (152)	156 (158)	154 (157)	157 (161)	151 (155)

Die Mounting Recommendations

Mounting and Bonding Recommendations

Marki MMICs should be attached directly to a ground plane with conductive epoxy. The ground plane electrical impedance should be as low as practically possible. This will prevent resonances and permit the best possible electrical performance. Datasheet performance is only guaranteed in an environment with a low electrical impedance ground.

Mounting - To epoxy the chip, apply a minimum amount of conductive epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip. Cure epoxy according to manufacturer instructions.

Wire Bonding - Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

Circuit Considerations – 50 Ω transmission lines should be used for all high frequency connections in and out of the chip. Wirebonds should be kept as short as possible, with multiple wirebonds recommended for higher frequency connections to reduce parasitic inductance. In circumstances where the chip more than .001” thinner than the substrate, a heat spreading spacer tab is optional to further reduce bondwire length and parasitic inductance.

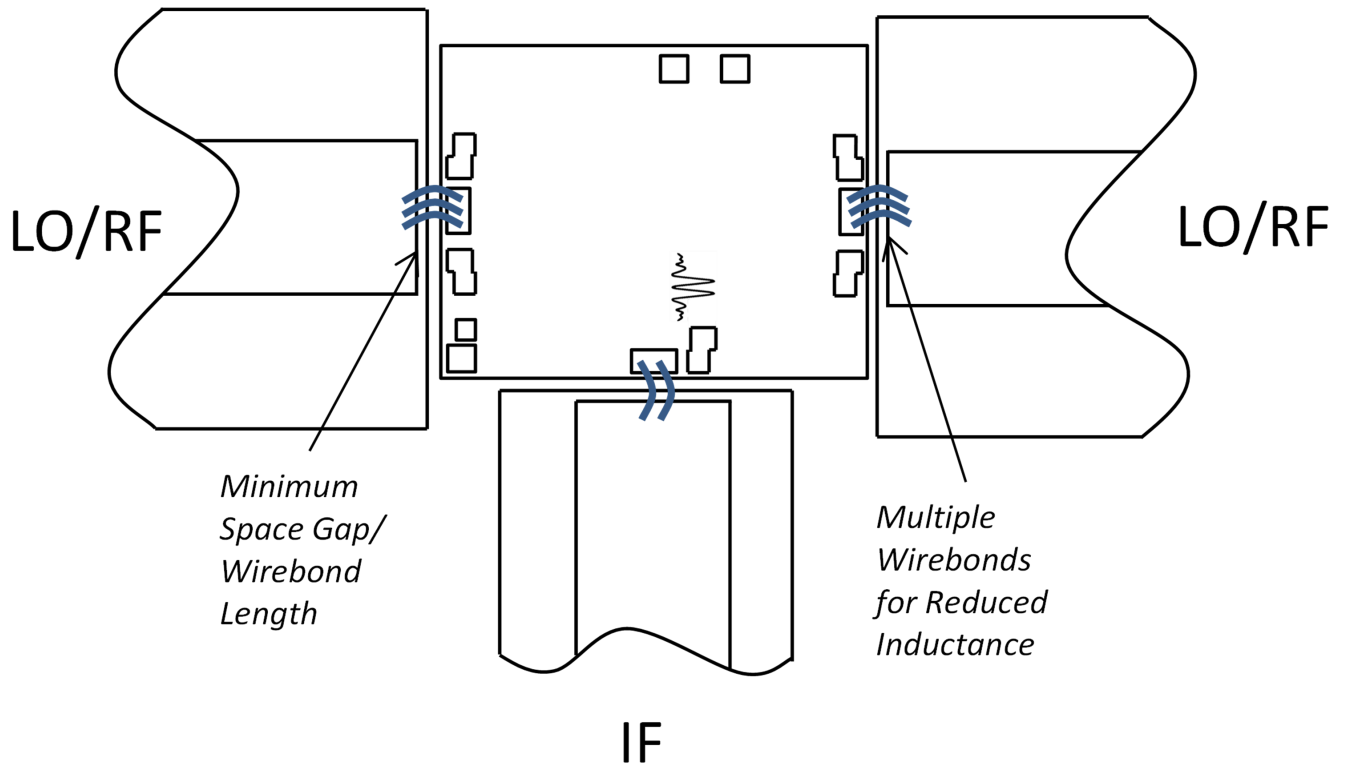
Handling Precautions

General Handling: Chips should be handled with a vacuum collet when possible, or with sharp tweezers using well trained personnel. The surface of the chip is fragile and should not be contacted if possible.

Static Sensitivity: GaAs MMIC devices are subject to static discharge, and should be handled, assembled, tested, and transported only in static protected environments.

Cleaning and Storage: Do not attempt to clean the chip with a liquid cleaning system or expose the bare chips to liquid. Once the ESD sensitive bags the chips are stored in are opened, chips should be stored in a dry nitrogen atmosphere.

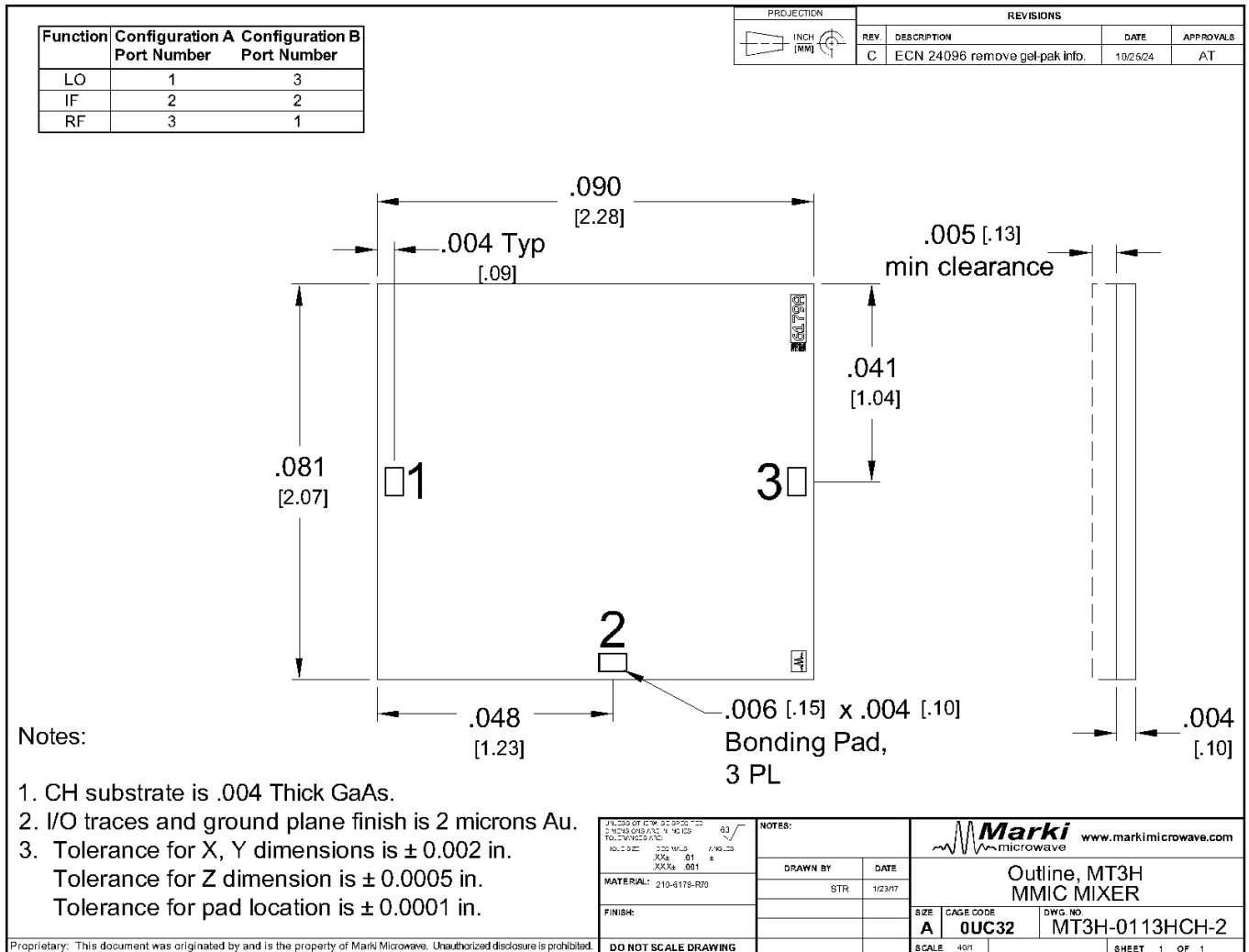
Bonding Diagram



Mechanical Data

Outline Drawing

Download : [Outline 2D Drawing](#)



Notes

1. Mixer Conversion Loss Plot IF frequency is 1 GHz unless otherwise specified.
2. Mixer Noise Figure typically measures within 0.5 dB of conversion loss for IF frequencies greater than 5 MHz.
3. Conversion Loss typically degrades less than 0.5 dB at +100°C and improves less than 0.5 dB at -55°C.
4. Unless otherwise specified, data is taken with highside, +20 dBm sine wave LO drive.
5. Square wave LO generated using 2x ADM1-0026PA with +10 dBm input into the first stage. LO Power reported in plots is of the fundamental tone only. Square wave LO power in plots is stepped down using broadband DC-40 GHz attenuators.
6. Specifications are subject to change without notice. Contact Marki Microwave for the most recent specifications and data sheets.
7. Catalog mixer circuits are continually improved. Configuration control requires custom mixer model numbers and specifications

Note: Exposure to maximum rating conditions for extended periods may reduce device reliability. There is no damage to device with only one parameter set at the limit and all other parameters set at or below their nominal value. Exceeding any of the limits listed here may result in permanent damage to the device.

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